## AM4840N

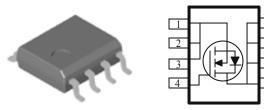
## **Analog Power**

## N-Channel 40-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize High Cell Density process. Low  $r_{DS(on)}$  assures minimal power loss and conserves energy, making this device ideal for use in power management circuitry. Typical applications are PWMDC-DC converters, power management in portable and battery-powered products such as computers, printers, battery charger, telecommunication power system, and telephones power system.

- Low r<sub>DS(on)</sub> Provides Higher Efficiency and Extends Battery Life
- Miniature SO-8 Surface Mount Package Saves Board Space
- High power and current handling capability
- Low side high current DC-DC Converter applications

PRODUCT SUMMARY			
V <sub>DS</sub> (V)	$r_{DS(on)} m(\Omega)$	I <sub>D</sub> (A)	
40	$22 @ V_{GS} = 10V$	9.7	
	$27 @ V_{GS} = 4.5V$	8.8	



ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Limit	Units	
Drain-Source Voltage		V <sub>DS</sub>	40	V	
Gate-Source Voltage		V <sub>GS</sub>	±20		
Continuous Drain Current <sup>a</sup>	T <sub>A</sub> =25°C	T	±9.7		
Continuous Drain Current	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	1 <sub>D</sub>	±7.2	А	
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	±50		
Continuous Source Current (Diode Conduction) <sup>a</sup>		I <sub>S</sub>	2.3	А	
Dever Dissingtion <sup>a</sup>	T <sub>A</sub> =25°C	D	3.1	W	
Power Dissipation <sup>a</sup>	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	1 D	2.2	vv	
Operating Junction and Storage Temperature Range			-55 to 150	°C	

THERMAL RESISTANCE RATING	S			
Parameter		Symbol	Maximum	Units
	t <= 10 sec	D	50	°C/W
Maximum Junction-to-Ambient <sup>a</sup>	Steady State	$R_{\theta JA}$	92	°C/W

Notes

a. Surface Mounted on 1" x 1" FR4 Board.

b. Pulse width limited by maximum junction temperature

Parameter	Sh al	Test Conditions	Limits			Unit	
Farameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \text{ uA}$	1			V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = 20 V$			±100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 24 V, V_{GS} = 0 V$			1	uA	
Zero Gute Voluge Dium Current	-D35	$V_{DS} = 24 V, V_{GS} = 0 V, T_J = 55^{\circ}C$			25	uЛ	
On-State Drain Current <sup>A</sup>	I <sub>D(on)</sub>	$V_{DS} = 5 V, V_{GS} = 10 V$	20			Α	
Drain-Source On-Resistance <sup>A</sup>	r <sub>DS(on)</sub>	$V_{GS} = 10 \text{ V}, I_D = 9.7 \text{ A}$			22	mΩ	
Drain-Source On-Resistance		$V_{GS} = 4.5 \text{ V}, I_D = 8.8 \text{ A}$			27	11152	
Forward Tranconductance <sup>A</sup>	g <sub>fs</sub>	$V_{DS} = 15 \text{ V}, I_D = 9.7 \text{ A}$		40		S	
Diode Forward Voltage	V <sub>SD</sub>	$I_{\rm S} = 2.3$ A, $V_{\rm GS} = 0$ V		0.7		V	
Dynamic <sup>b</sup>							
Total Gate Charge	Qg	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V},$		12.5		nC	
Gate-Source Charge	Q <sub>gs</sub>	$I_D = 9.7 \text{ A}$		2.6			
Gate-Drain Charge	Q <sub>gd</sub>	1) 7.7 1		4.6			
Switching							
Turn-On Delay Time	t <sub>d(on)</sub>			20		nS	
Rise Time	t <sub>r</sub>	$V_{DD} = 25 \text{ V},  \text{R}_{\text{L}} = 25 \Omega ,  \text{I}\text{D} = 1  \text{A},$		9			
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GEN} = 10 V$		70			
Fall-Time	t <sub>f</sub>			20			

Notes

- a. Pulse test:  $PW \le 300$  us duty cycle  $\le 2\%$ .
- b. Guaranteed by design, not subject to production testing.

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